

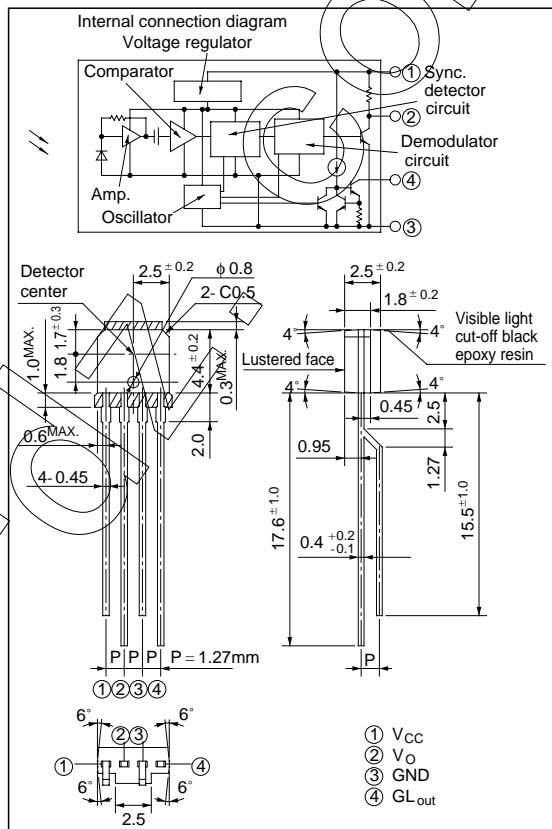
IS471F

OPIC Light Detector with Built-in Signal Processing Circuit for Light Modulation System

■ Features

1. Impervious to external disturbing lights due to light modulation system
2. Built-in pulse driver circuit and sync. detector circuit on the emitter side
3. A wide range of operating supply voltage (V_{cc}: 4.5 to 16V)

■ Outline Dimensions



OPIC (Optical IC) is a trademark of the SHARP Corporation.
An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

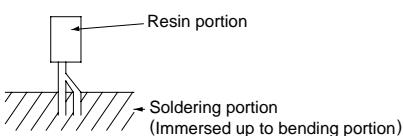
■ Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Supply voltage	V _{cc}	-0.5 to 16	V
Output	Output voltage	V _o	V
	Output current	I _o	mA
*1 GL output	Output voltage	V _{GL}	V
Power dissipation	P	250	mW
Operating temperature	T _{opr}	-25 to +60	°C
Storage temperature	T _{stg}	-40 to +100	°C
*2 Soldering temperature	T _{sol}	260	°C

*1 Applies to G_L_{out} terminal

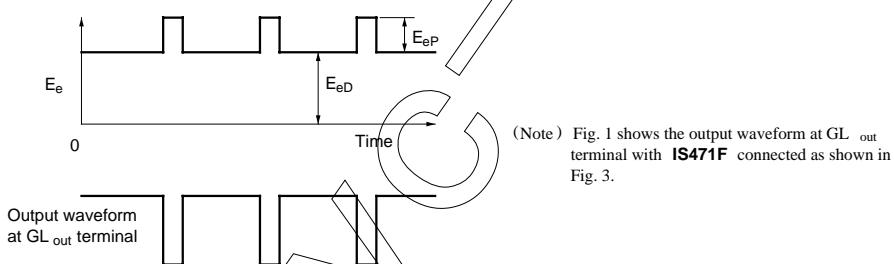
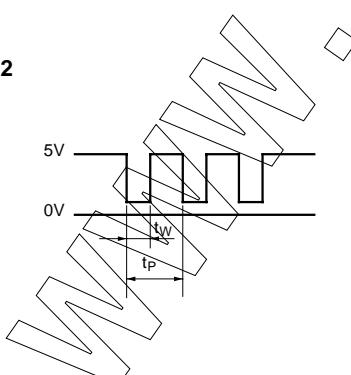
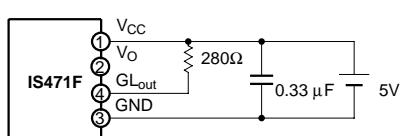
*2 For 5 seconds at the position shown in the right figure



■ Electro-optical Characteristics

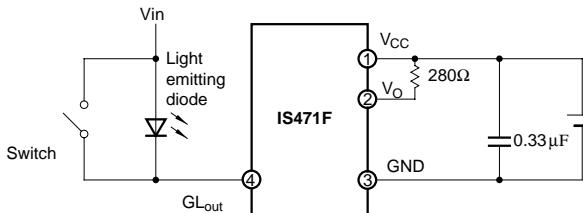
(V_{CC}= 5V, Ta= 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating supply voltage	V _{CC}	-	4.5	-	16	V
Supply current	I _{CC}	V _O , GL _{out} terminals shall be opened.	-	3.5	7.0	mA
Output	Low level output voltage	V _{OL}	I _{OL} = 16mA, E _{VP} = 500lx, E _{VD} = 0 ^{*3}	-	0.15	0.35
	High level output voltage	V _{OH}	E _{VD} = E _{VP} = 0 ^{*3}	4.97	-	V
	Output short circuit current	I _{OS}	E _{VP} = E _{VD} = 0 ^{*3}	0.25	0.5	mA
GL output	Low level output current	I _{GL}	V _{GL} = 1.2V	40	55	79
	^{*4} Pulse cycle	t _P	-	70	130	220
	^{*4} Pulse width	t _W	-	4.4	8	13.7
^{*5} "Low→High" threshold irradiance	E _{ePLH}	E _{eD} = 0 ^{*3}	-	0.4	2.66	μW/mm ²
^{*5} "High→Low" threshold irradiance	E _{ePHL}	Light emitting diode (λ p= 940nm) ^{*6}	-	0.7	2.8	μW/mm ²
Hysteresis	E _{ePLH} /E _{ePHL}		0.45	0.65	0.95	-
Response time	"High→Low" propagation delay time	t _{PHL}	*6	-	400	670
	"Low→High" propagation delay time	t _{PLH}	*6	-	400	670
^{*7} External disturbing light illuminance	E _{VDX}	E _{eP} = 7.5 μ W/mm ² , ^{*3} λ p= 940nm	2000	7500	-	lx

^{*3} E_{eP} represents illuminance of signal light in sync with the low level timing of output at GL_{out} terminal.E_{eD} represents illuminance of DC light. For detail, see Fig. 1.Light source: Infrared light emitting diode (λ p= 940nm)E_{VP} represents illuminance of signal light in sync with the low level timing of output at GL_{out} terminal.E_{VD} represents illuminance of DC light. Note that the light source is CIE standard light source X.**Fig.1**^{*4} Pulse cycle (t_P), pulse width (t_W) are defined as shown in Fig. 2.The waveform shown in Fig. 2 is the output voltage waveform at GL_{out} terminal with IS471F connected as shown in Fig. 3.**Fig.2**^{*5} Defined as E_{eP} that causes the output to go " Low to High" (or " High to Low").**Fig.3**

*6 Test circuit for response time, threshold irradiance is shown in Fig. 4.

Fig. 4



Light emitting diode : peak emission wavelength $\lambda_p = 940\text{nm}$

*7 E_{VDX} : Defined as the E_{VD} at the limit of normal operation range.

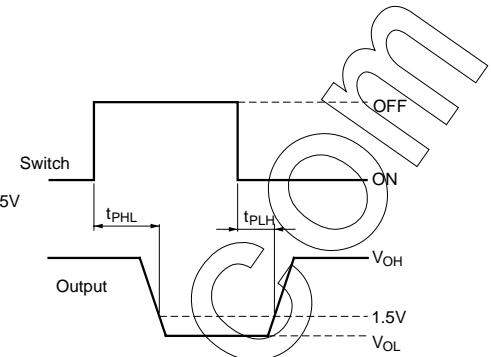


Fig. 5 Power Dissipation vs. Ambient Temperature

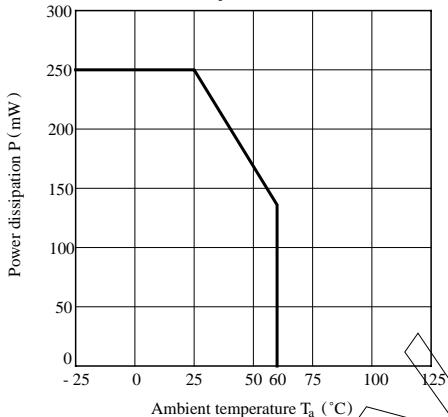


Fig. 7 Low Level Output Voltage vs. Ambient Temperature

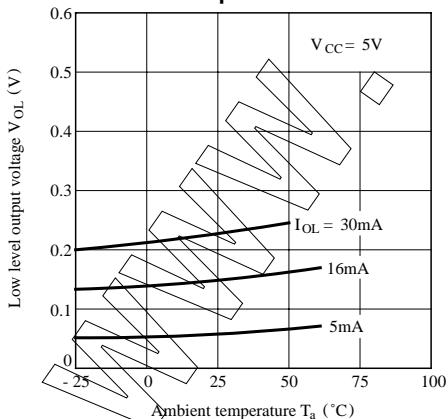


Fig. 6 Low Level Output Voltage vs. Low Level Output Current

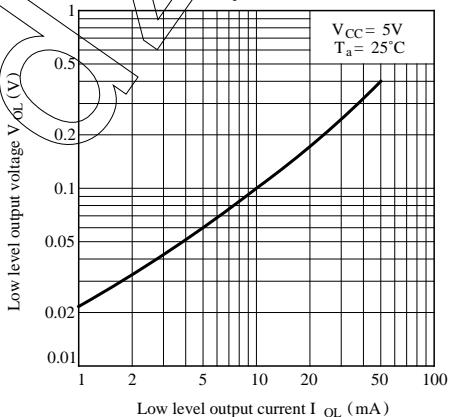


Fig. 8 Supply Current vs. Supply Voltage

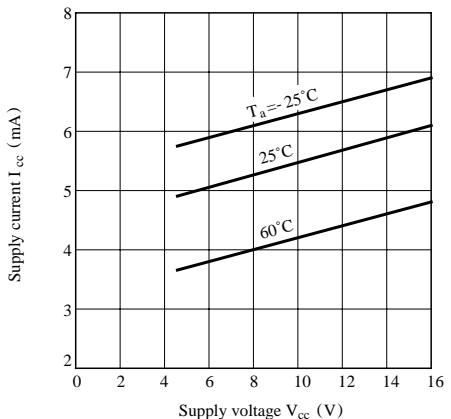


Fig. 9 Low Level Output Current vs. Supply Voltage

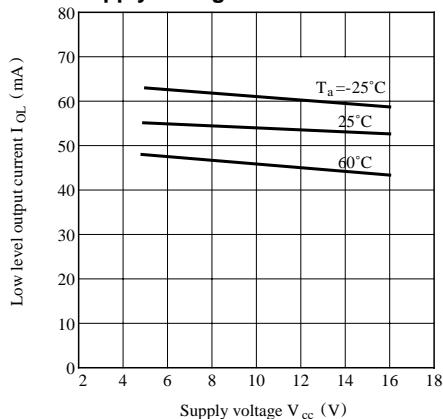


Fig.10 Sensitivity Diagram ($T_a = 25^{\circ}\text{C}$)

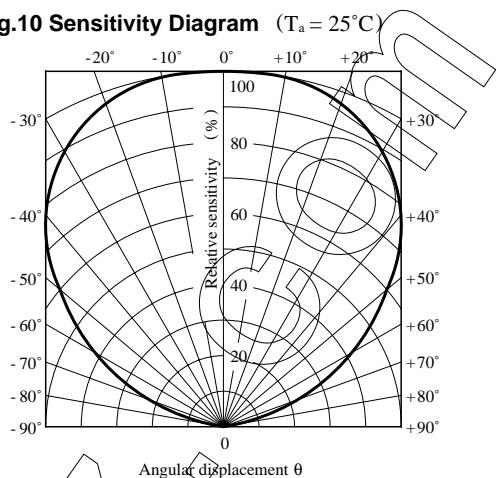
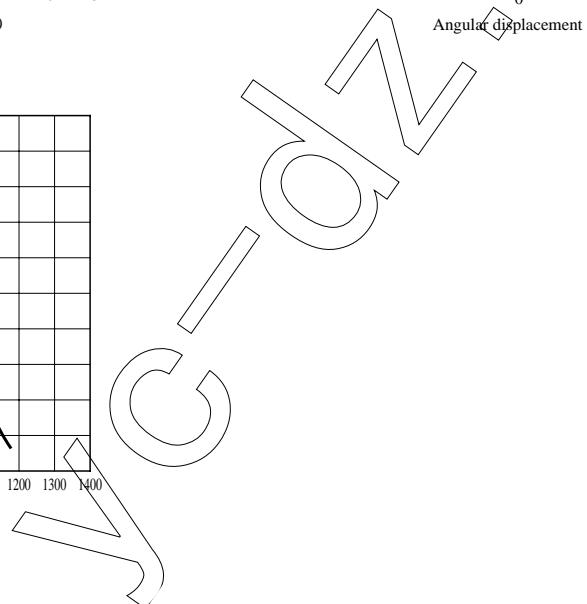
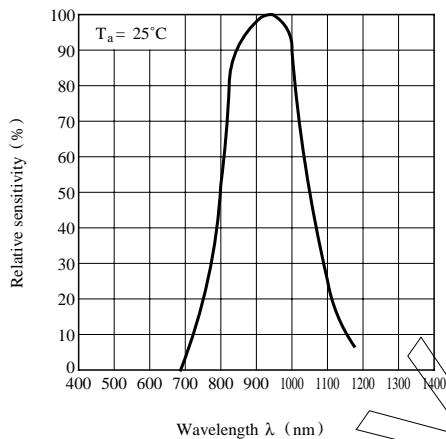
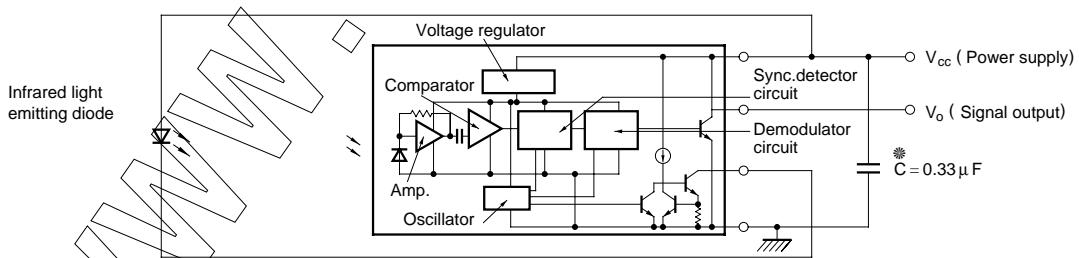


Fig.11 Spectral Sensitivity



■ Basic Circuit



※ In order to stabilize power supply line, connect a by-pass capacitor of $0.33\mu\text{F}$ or more between V_{cc} and GND near the device.

● Please refer to the chapter "Precautions for Use."